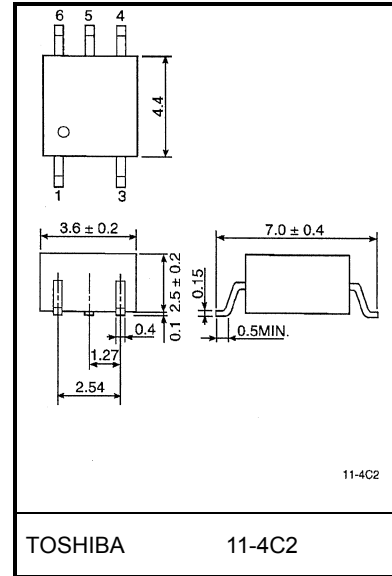


# TLP117

PDP (Plasma Display Panel)  
 FA (Factory Automation)  
 High-Speed Interface

The Toshiba TLP117 consists of a GaAlAs light-emitting diode and an integrated high-gain, high-speed photodetector.

- Inverter logic (totempole output)
- Package type : MFSOP6
- Guaranteed performance over temperature : -40 to 105°C
- Power supply voltage : 4.5 to 5.5V
- Input thresholds current :  $I_{FHL}=5mA(Max.)$
- Propagation delay time (tpHL/tpLH) : 30ns(Max.) at VL=0V
- 20ns(Max.) at VL=1.1V
- Switching speed : 50MBd(TYP.)
- Common mode transient immunity : 10kV/μs (Min.)
- Isolation voltage : 3750Vrms
- UL Recognized : UL1577,File No.E67349

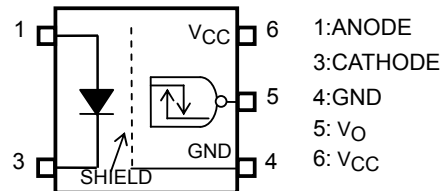


Weight: 0.09 g(Typ.)

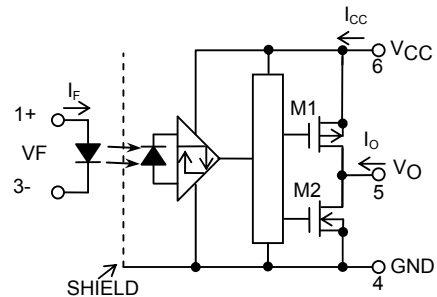
**Truth Table**

Input	LED	M1	M2	Output
H	ON	OFF	ON	L
L	OFF	ON	OFF	H

**Pin Configuration (Top View)**



**Schematic**



0.1μF bypass capacitor must be connected between pins 6 and 4

**Absolute Maximum Ratings (Ta=25°C)**

Characteristic		Symbol	Rating	Unit
LED	Forward current	I <sub>F</sub>	25	mA
	Forward current derating (Ta≥85°C)	ΔI <sub>F</sub> /ΔTa	-0.7	mA/°C
	Peak transient forward current (Note1)	I <sub>FPT</sub>	1	A
	Reverse voltage	V <sub>R</sub>	6	V
DETECTOR	Output current	I <sub>O</sub>	10	mA
	Output voltage	V <sub>O</sub>	6	V
	Supply voltage	V <sub>CC</sub>	6	V
	Output power dissipation	P <sub>O</sub>	40	mW
Operating temperature range		T <sub>opr</sub>	-40 to 105	°C
Storage temperature range		T <sub>stg</sub>	-55 to 125	°C
Lead solder temperature(10s)		T <sub>sol</sub>	260	°C
Isolation voltage (AC, 1min., R.H.≤60%, Ta=25°C) (Note2)		BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Pulse width PW≤1μs,300pps.

Note2: This device is regarded as a two-terminal device: pins 1 and 3 are shorted together, and pins 4,5 and 6 are shorted together.

**Recommended Operating Conditions**

Characteristic	Symbol	Min	Typ.	Max	Unit
Input current , ON	I <sub>F(ON)</sub>	10	—	16	mA
Input voltage , OFF	V <sub>F(OFF)</sub>	0	—	1.0	V
Supply voltage(*) (Note3)	V <sub>CC</sub>	4.5	5.0	5.5	V

\* This item denotes operating ranges, not meaning of recommended operating conditions.

Note : Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note3 : The detector of this product requires a power supply voltage (V<sub>CC</sub>) of 4.5 V or higher for stable operation. If V<sub>CC</sub> is lower than this value, I<sub>CC</sub> may increase or the output may be unstable.

Be sure to use the product after checking the supply current, and the operation of a power-on/-off.

## Electrical Characteristics

(Unless otherwise specified, Ta=-40 to 105°C, VCC =4.5 to 5.5V)

Characteristic		Symbol	Test Circuit	Conditions	Min.	Typ.	Max.	Unit
Input forward voltage		V <sub>F</sub>	—	I <sub>F</sub> =10mA, Ta=25°C	1.45	1.6	1.85	V
Temperature coefficient of forward voltage		ΔV <sub>F</sub> /ΔTa	—	I <sub>F</sub> =10mA	—	-2.0	—	mV/°C
Input reverse current		I <sub>R</sub>	—	V <sub>R</sub> =5V, Ta=25°C	—	—	10	μA
Input capacitance		C <sub>T</sub>	—	V=0, f=1MHz, Ta=25°C	—	60	—	pF
Output voltage	"L" Level	V <sub>OL</sub>	1	I <sub>OL</sub> =4mA, I <sub>F</sub> =10mA	—	—	0.6	V
	"H" Level	V <sub>OH</sub>	2	I <sub>OH</sub> =-4mA, V <sub>F</sub> =1.05V, V <sub>CC</sub> =4.5V V <sub>CC</sub> =5.5V	3.9 4.9	— —	— —	V
Supply current	"L" Level	I <sub>CCL</sub>	3	I <sub>F</sub> =10mA	—	—	5.0	mA
	"H" Level	I <sub>CCH</sub>	4	V <sub>F</sub> =0V	—	—	5.0	mA
Input current		H → L	—	I <sub>O</sub> =20μA, V <sub>O</sub> <0.3V	—	—	5	mA
Input voltage		L → H	—	I <sub>O</sub> =-20μA, V <sub>O</sub> >4.0V	0.8	—	—	V

\*All typical values are at Ta=25°C unless otherwise specified.

## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Capacitance input to output	C <sub>S</sub>	V = 0, f = 1MHz (Note 2)	—	0.8	—	pF
Isolation resistance	R <sub>S</sub>	R.H. ≤ 60%, V <sub>S</sub> = 500V (Note 2)	1×10 <sup>12</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BV <sub>S</sub>	AC, 1 minute	3750	—	—	V <sub>rms</sub>
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V <sub>dc</sub>

Note 4: A ceramic capacitor (0.1 μF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypass may impair the switching property.  
The total lead length between capacitor and coupler should not exceed 1 cm.

Switching Characteristics

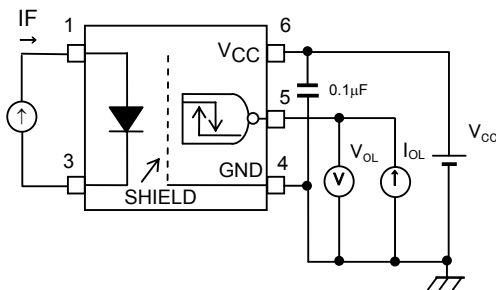
(Unless otherwise specified,  $T_a = -40$  to  $105^\circ\text{C}$ ,  $V_{CC} = 4.5$  to  $5.5\text{V}$ )

Characteristic	Symbol	Test Circuit	Conditions	Min.	Typ.	Max.	Unit	
Propagation delay time to logic high output	tpHL	5	$V_{IN} = 0$ to $5\text{V}$	—	—	30	ns	
Propagation delay time to logic low output	tpLH		$V_{IN} = 5$ to $0\text{V}$	—	—	30	ns	
Switching time dispersion between ON and OFF	tpHL-tpLH		—	$R_{IN} = 360\ \Omega$ $C_{IN} = 22\text{pF}$ $V_L = 0\text{V}$ (Note 5)	—	—	10	ns
Output fall time(90-10%)	tf		$V_{IN} = 0$ to $5\text{V}$	—	3	—	ns	
Output rise time(10-90%)	tr		$V_{IN} = 5$ to $0\text{V}$	—	2	—	ns	
Propagation delay time to logic high output	tpHL	6	$V_{IN} = 1.1$ to $5\text{V}$	—	—	20	ns	
Propagation delay time to logic low output	tpLH		$V_{IN} = 5$ to $1.1\text{V}$	—	—	20	ns	
Propagation delay skew	tpsk		—	$R_{IN} = 360\ \Omega$ $C_{IN} = 22\text{pF}$ $V_L = 1.1\text{V}$ (Note 5)	—	—	16	ns
Switching time dispersion between ON and OFF	tpHL-tpLH		—	—	—	2	8	ns
Output fall time(90-10%)	tf		$V_{IN} = 1.1$ to $5\text{V}$	—	3	—	ns	
Output rise time(10-90%)	tr		$V_{IN} = 5$ to $1.1\text{V}$	—	3	—	ns	
Data rate	T		—	—	—	50	—	MBd
Common mode transient immunity at high Level output	CM <sub>H</sub>	7	$V_{CM} = 1000\text{Vp-p}$ , $T_a = 25^\circ\text{C}$ $I_F = 0\text{mA}$ , $V_{CC} = 5\text{V}$ , $V_O(\text{Min}) = 4\text{V}$ ,	10000	—	—	V/ $\mu\text{s}$	
Common mode transient immunity at low level output	CM <sub>L</sub>		$V_{CM} = 1000\text{Vp-p}$ , $T_a = 25^\circ\text{C}$ $I_F = 10\text{mA}$ , $V_{CC} = 5\text{V}$ , $V_O(\text{Max}) = 0.4\text{V}$	-10000	—	—	V/ $\mu\text{s}$	

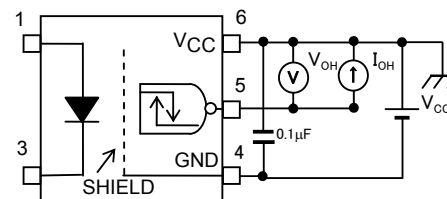
\*All typical values are at  $T_a = 25^\circ\text{C}$ ,  $V_{CC} = 5\text{V}$ .

Note 5 :  $C_L$  is approximately 15pF which includes probe and Jig/stray wiring capacitance.

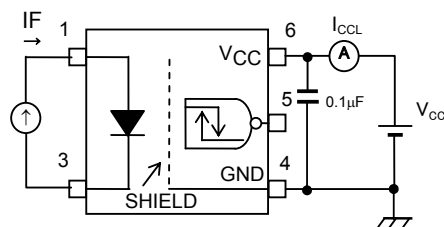
TEST CIRCUIT 1 :  $V_{OL}$



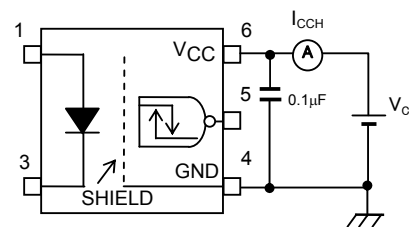
TEST CIRCUIT 2 :  $V_{OH}$



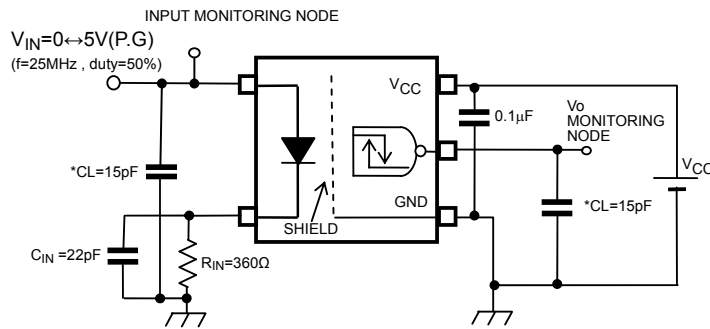
TEST CIRCUIT 3 :  $I_{CCL}$



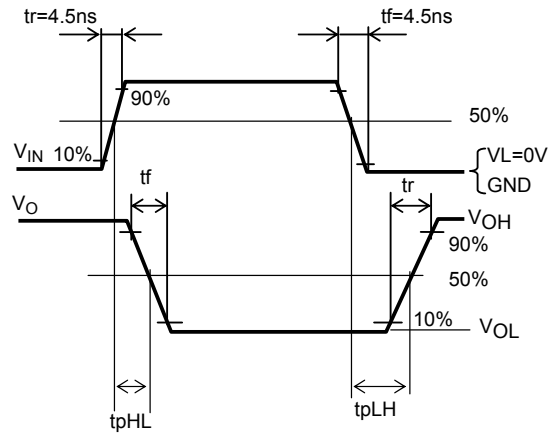
TEST CIRCUIT 4 :  $I_{CCH}$



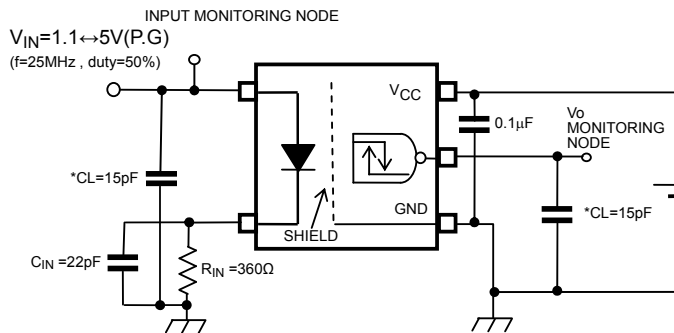
## TEST CIRCUIT 5 : tpHL , tpLH



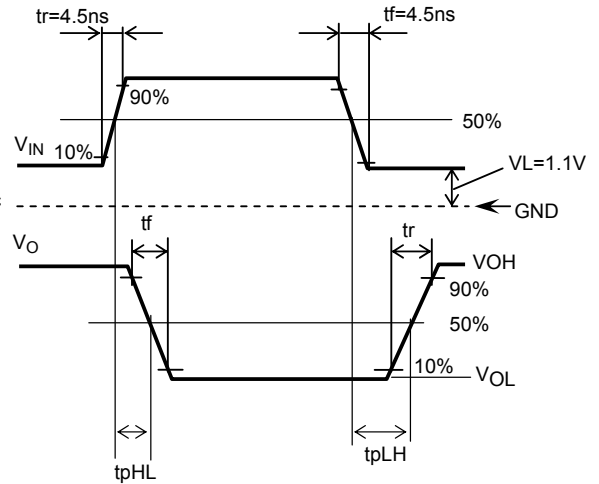
CL is capacitance of the probe and JIG.  
(P.G) : Pulse Generator



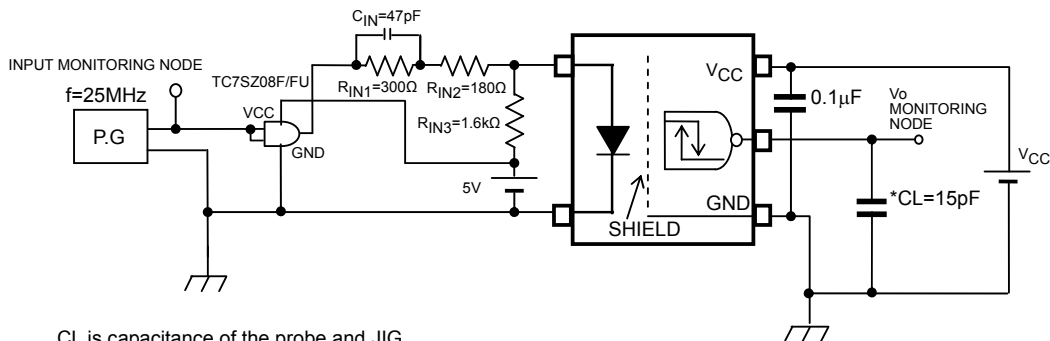
## TEST CIRCUIT 6 : tpHL , tpLH



CL is capacitance of the probe and JIG.  
(P.G) : Pulse Generator

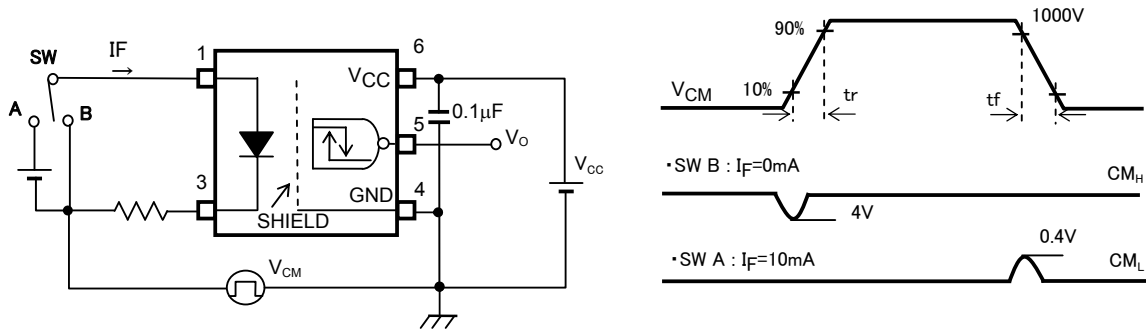


(example for LED drive circuit)



CL is capacitance of the probe and JIG.  
(P.G) : Pulse Generator

TEST CIRCUIT 7 : Common-Mode Transient Immunity Test Circuit



$$CM_H = \frac{800(V)}{t_r(\mu s)} \quad CM_L = \frac{800(V)}{t_f(\mu s)}$$

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